









# **CEZ1320P**

#### -200V ▲ 280mΩ ▲ -12.5A ▲ Si MOSFET

SILICON Si MOSFET ▲ SMD type
P-channel enhancement mode
UL94V-0 rated flame retardant epoxy
PPAK5x6 package ▲ MSL 3
Super high dense cell density for extremely low R<sub>DS(ON)</sub>

High power and current handling capability

## **MAXIMUM RATINGS**

| Parameter (T <sub>C</sub> = 25°C, unless otherwise noted) |                                   | Characteristics |
|---|-----------------------------------|-----------------|
| Drain-Source Voltage                                      | V <sub>DS</sub>                   | -200V           |
| Gate-Source Voltage                                       | V <sub>GS</sub>                   | ±30V            |
| Continuous Drain Current at R <sub>TH_JC</sub>            | I <sub>D</sub>                    | -12.5A          |
| Continuous Drain Current at R <sub>TH_JA</sub>            | I <sub>D</sub>                    | -3.2A           |
| Pulsed Drain Current at R <sub>TH_JC</sub> Note 1         | I <sub>DM</sub>                   | -50A            |
| Pulsed Drain Current at R <sub>TH_JA</sub> Note 1         | I <sub>DM</sub>                   | -12.8A          |
| Maximum Power Dissipation                                 | P <sub>D</sub>                    | 96W             |
| Single Pulsed Avalanche Energy Note 5                     | E <sub>AS</sub>                   | 165mJ           |
| Single Pulsed Avalanche Current Note 5                    | I <sub>AS</sub>                   | 10.5A           |
| Operating and Storage Temperature Range                   | T <sub>J</sub> , T <sub>STG</sub> | -55°C to +150°C |

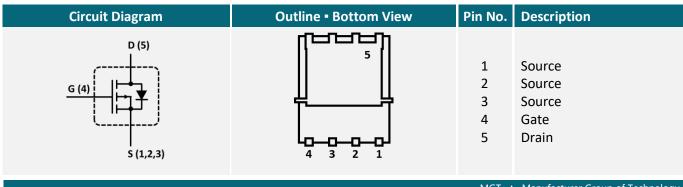
#### THERMAL CHARACTERISTICS

| Parameter                                      | Symbol             | Limit   |
|--|--------------------|---------|
| Thermal Resistance, Junction-to-Case           | R <sub>TH_JC</sub> | 1.3°C/W |
| Thermal Resistance, Junction-to-Ambient Note 2 | R <sub>TH JA</sub> | 20°C/W  |

## **APPLICATIONS**

| ССТУ | Large    | Pico  | Power over | WIFI     |
|------|----------|-------|------------|----------|
|      | Displays | Cells | Ethernet   | Hotspots |
|      |          | 5G/6G | PoE        | WIFI     |

## **PIN DESCRIPTION**





## **ELECTRICAL CHARACTERISTICS** ▲ T<sub>C</sub> = 25°C, unless otherwise noted

| Item   | Condition   | Symbol              | Min. | Тур. | Max.  | Unit |  |  |  |
|--|---|---------------------|------|------|-------|------|--|--|--|
| Off Characteristics                          |   |                     |      |      |       |      |  |  |  |
| Drain-Source Breakdown Voltage               | $V_{GS} = 0V$ , $I_D = -250\mu A$   | $BV_DSS$            | -200 |      |       | V    |  |  |  |
| Zero Gate Voltage Drain Current              | $V_{DS} = -200V$ , $V_{GS} = 0V$  | I <sub>DSS</sub>    |      |      | -1    | μΑ   |  |  |  |
| Gate Body Leakage Current, Forward           | $V_{GS}$ = 30V, $V_{DS}$ = 0V   | $I_{GSSF}$          |      |      | 100   | nA   |  |  |  |
| Gate Body Leakage Current, Reverse           | $V_{GS} = -30V, V_{DS} = 0V$  | $I_{GSSR}$          |      |      | -100  | nA   |  |  |  |
| On Characteristics Note 3                    |   |                     |      |      |       |      |  |  |  |
| Gate Threshold Voltage                       | $V_{GS} = V_{DS}$ , $I_{D} = -250 \mu A$  | $V_{GS(th)}$        | -2   |      | -4    | V    |  |  |  |
| Static Drain-Source On-Resistance            | $V_{GS} = -10V$ , $I_D = -5.2A$   | R <sub>DS(ON)</sub> |      | 280  | 360   | mΩ   |  |  |  |
| Dynamic Characteristics Note 4               |   |                     |      |      |       |      |  |  |  |
| Input Capacitance                            | $V_{DS} = -25V$ , $V_{GS} = 0V$ , $f = 1MHz$                                    | C <sub>ISS</sub>    |      | 1620 |       | pF   |  |  |  |
| Output Capacitance                           | $V_{DS} = -25V$ , $V_{GS} = 0V$ , $f = 1MHz$                                    | Coss                |      | 240  |       | рF   |  |  |  |
| Reverse Transfer Capacitance                 | $V_{DS} = -25V$ , $V_{GS} = 0V$ , $f = 1MHz$                                    | $C_{RSS}$           |      | 50   |       | pF   |  |  |  |
| Switching Characteristics Note 4             |   |                     |      |      |       |      |  |  |  |
| Turn-On Delay Time                           | $V_{DD}$ = -100V, $V_{GS}$ = -10V, $I_{D}$ = -13.5A, $R_{G(ext)}$ = 25 $\Omega$ | $t_{D(ON)}$         |      | 28   |       | ns   |  |  |  |
| Turn-On Rise Time                            | $V_{DD}$ = -100V, $V_{GS}$ = -10V, $I_{D}$ = -13.5A, $R_{G(ext)}$ = 25 $\Omega$ | $t_R$               |      | 74   |       | ns   |  |  |  |
| Turn-Off Delay Time                          | $V_{DD}$ = -100V, $V_{GS}$ = -10V, $I_D$ = -13.5A, $R_{G(ext)}$ = 25 $\Omega$   | $t_{\text{D(OFF)}}$ |      | 260  |       | ns   |  |  |  |
| Turn-Off Fall Time                           | $V_{DD}$ = -100V, $V_{GS}$ = -10V, $I_{D}$ = -13.5A, $R_{G(ext)}$ = 25 $\Omega$ | t <sub>F</sub>      |      | 120  |       | ns   |  |  |  |
| Total Gate Charge                            | $V_{DD} = -160V$ , $V_{GS} = -10V$ , $I_D = -13.5A$                             | $Q_{G}$             |      | 52   |       | nC   |  |  |  |
| Gate Source Charge                           | $V_{DD} = -160V$ , $V_{GS} = -10V$ , $I_D = -13.5A$                             | $Q_{GS}$            |      | 9    |       | nC   |  |  |  |
| Gate Drain Charge                            | $V_{DD}$ = -160V, $V_{GS}$ = -10V, $I_D$ = -13.5A                               | $Q_{GD}$            |      | 25   |       | nC   |  |  |  |
| Drain-Source Diode Characteristics and       | Drain-Source Diode Characteristics and Maximum Ratings                          |                     |      |      |       |      |  |  |  |
| Drain-Source Diode<br>Forward Current Note 2 |   | I <sub>S</sub>      |      |      | -12.5 | Α    |  |  |  |
| Drain-Source Diode<br>Forward Voltage Note 3 | $V_{GS} = 0V$ , $I_S = -12.5A$  | $V_{\text{SD}}$     |      |      | -1.2  | V    |  |  |  |

#### **Notes**

- 1: Repetitive Rating: Pulse width limited by maximum junction temperature
- 2: Surface Mounted on FR4 Board, t ≤ 10 sec
- 3: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4: Guaranteed by design, not subject to production testing.
- 5: L = 3mH,  $I_{AS}$  = 10.5A,  $V_{DD}$  = 25V,  $R_G$  = 25Ω, Starting  $T_J$  = 25°C



### REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

10

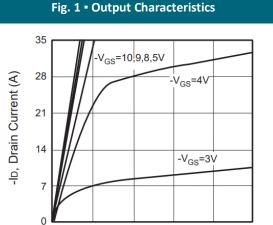


Fig. 2 • Transfer Characteristics

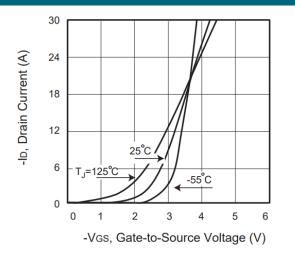


Fig. 3 • Capacitance

-VDS, Drain-to-Source Voltage (V)

0

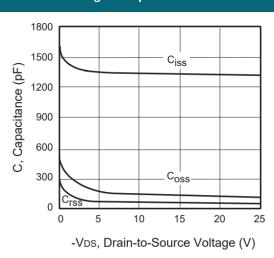


Fig. 4 • On-Resistance Variation with Temperature

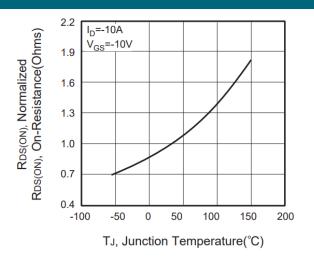


Fig. 5 • Gate Threshold Variation with Temperature

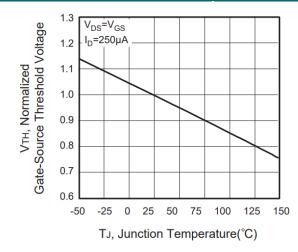
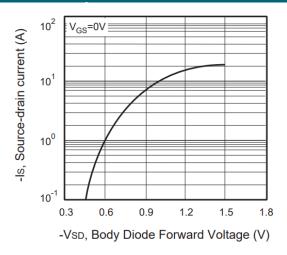


Fig. 6 • Body Diode Forward Voltage Variation with Source Current



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#### REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

Fig. 7 • Gate Charge

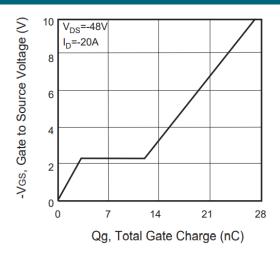


Fig. 8 • Maximum Safe Operating Area

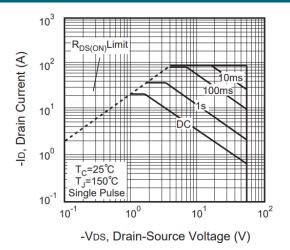


Fig. 9 • Breakdown Voltage Variation vs. Temperature

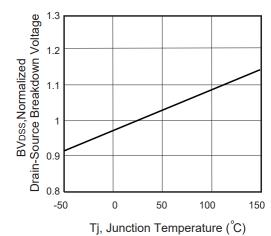




Fig. 10 • Switching Test Circuit

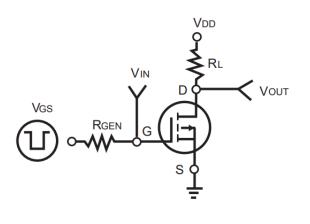
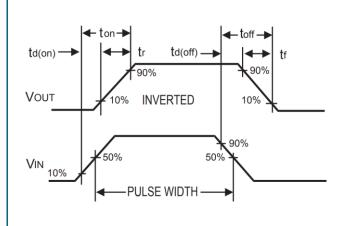


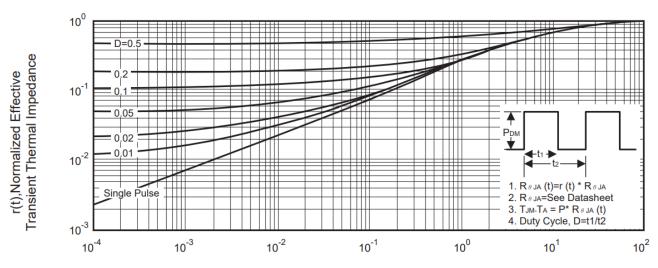
Fig. 11 • Switching Waveforms





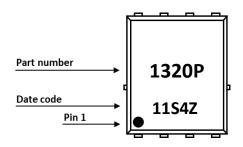
#### REFERENCE DATA A TYPICAL DEVICE PERFORMANCE

Fig. 12 • Normalized Thermal Transient Impedance Curve



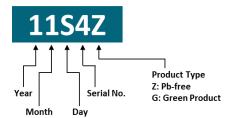
Square Wave Pulse Duration (sec)

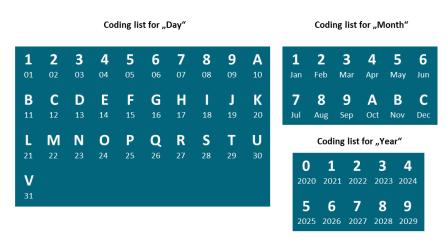
#### **PART MARKING**



#### **DATE CODE**

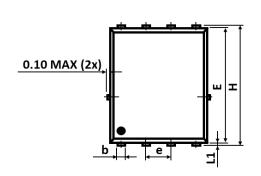
Example: 11S4Z

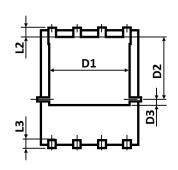


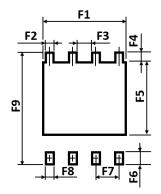


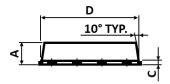


## PACKAGE OUTLINE AND RECOMMENDED PAD LAYOUT









| Sym | Millimeters<br>(Min.) | Millimeters<br>(Typ.) | Millimeters (Max.) |
|-----|-----------------------|-----------------------|--------------------|
| Α   | 0.800                 | -                     | 1.170              |
| b   | 0.340                 | -                     | 0.490              |
| С   | 0.200                 | -                     | 0.340              |
| D   | 4.800                 | -                     | 5.100              |
| D1  | 3.800                 | -                     | 4.200              |
| D2  | 3.180                 | -                     | 3.780              |
| D3  | 0.150                 | _                     | 0.360              |

| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|--------------------|--------------------|--------------------|
| E   | 5.650              | -                  | 5.900              |
| e   |                    | 1.270 TYP          |                    |
| Н   | 5.900              | -                  | 6.150              |
| L1  | 0.050              | -                  | 0.250              |
| L2  | 0.380              | -                  | 0.620              |
| L3  | 0.380              | -                  | 0.750              |

| Sym | Millimeters (Min.) | Millimeters (Typ.) | Millimeters (Max.) |
|-----|--------------------|--------------------|--------------------|
| F1  | -                  | 4.500              | -                  |
| F2  | -                  | 0.500              | -                  |
| F3  | -                  | 0.770              | -                  |
| F4  | -                  | 0.550              | -                  |
| F5  | -                  | 3.650              | -                  |

| Millimeters (Min.) | Millimeters (Typ.) | Millimeters<br>(Max.)                    |
|--------------------|--------------------|--|
| -                  | 0.800              | -  |
| -                  | 1.270              | -  |
| -                  | 0.500              | -  |
| -                  | 6.250              | -  |
|                    |                    | (Min.) (Typ.)  - 0.800  - 1.270  - 0.500 |

Notes: 1. The suggested land pattern dimensions have been provided for reference only.

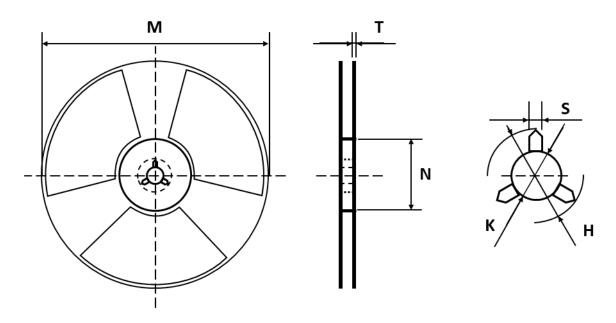
2. For further information, please reference document IPC-7351A.

## **ORDERING INFORMATION**

| Part Number | Package  | Packing | Reel Qty. | Inner Box Qty. | Outer Box Qty. |
|-------------|----------|---------|-----------|----------------|----------------|
| CEZ1320P    | PPAK 5x6 | Reel    | 2,500pcs  | 5,000pcs       | 40,000pcs      |

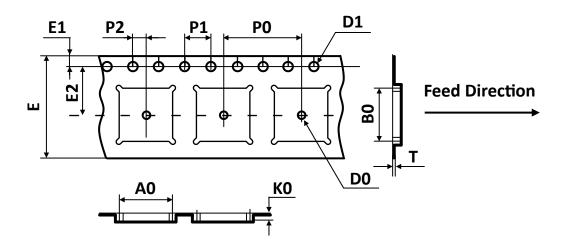


## **REEL DIMENSIONS** ▲ All dimensions in mm



| Tape Size | Reel Size | M       | N       | T     | H     | К              | S     |
|-----------|-----------|---------|---------|-------|-------|----------------|-------|
|           |           | Ø330.00 | Ø100.00 | 2.10  | 22.00 | 13.00          | 2.00  |
| 12mm      | Ø330      | ±2.00   | ±1.00   | ±0.20 | ±0.50 | +0.50<br>-0.20 | ±0.50 |

# **TAPE DIMENSIONS** ▲ All dimensions in mm

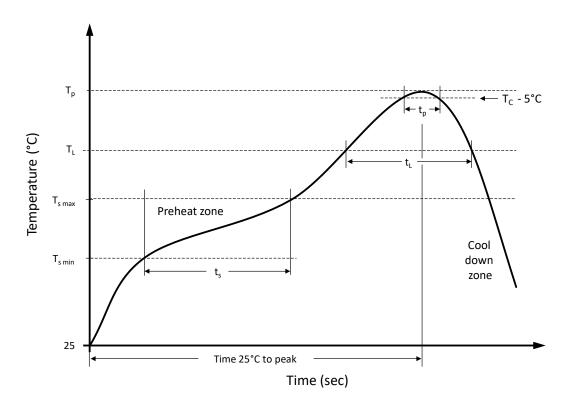


| Package  | Α0    | В0    | КО    | D0    | D1    | Е     | E1    | E2    | P0    | P1    | P2    | T     |
|----------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
|          | 6.50  | 5.28  | 2.00  | 1.50  | 1.50  | 12.00 | 1.75  | 5.50  | 8.00  | 4.00  | 2.00  | 0.25  |
| PPAK 5x6 | ±0.10 | ±0.10 | ±0.10 | ±0.25 | ±0.10 | +0.30 | ±0.10 | ±0.05 | ±0.10 | ±0.10 | ±0.05 | ±0.02 |

Note: All dimensions meet EIA-481-D requirements.



## RECOMMENDED REFLOW SOLDERING PROFILE



## **Recommended reflow soldering conditions** ▲ **Refer to JEDEC J-STD-020E**

| Profile Features  |                    | Sn-Pb Eutetic Assembly | Pb-Free Assembly |
|---|--------------------|------------------------|------------------|
| Preheat temperature min.  | $T_{s min}$        | 100 °C                 | 150 °C           |
| Preheat temperature max.  | T <sub>s max</sub> | 150 °C                 | 200 °C           |
| Preheat time t <sub>s</sub> from T <sub>s min</sub> to T <sub>s max</sub> | ts                 | 120 seconds            | 120 seconds      |
| Ramp-up rate (T₁ to Tp)   |                    | max. 3 °C/second       | max. 3 °C/second |
| Liquidous temperature   | $T_L$              | 183 °C                 | 217 °C           |
| Time t <sub>L</sub> maintained above T <sub>L</sub>                       | t <sub>L</sub>     | 150 seconds max.       | 150 seconds max. |
| Peak package body temperature   | Tp                 | 235°C                  | 260°C            |
| Timeframe of within 5°C below and up to max actual peak body temperature  | t <sub>p</sub>     | 20 seconds max.        | 30 seconds max.  |
| Ramp-down rate (T <sub>L</sub> to T <sub>p</sub> )                        |                    | max. 6 °C/second       | max. 6 °C/second |
| Time 25°C to peak temperature   |                    | max. 6 minutes         | max. 8 minutes   |



#### **REVISION TABLE**

| Revision | Date       | Status          | Notes               |
|----------|------------|-----------------|---------------------|
| 001      | 30/09/2022 | Initial release | Initial publication |
|          |            |                 |                     |
|          |            |                 |                     |
|          |            |                 |                     |
|          |            |                 |                     |
|          |            |                 |                     |

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